

# C4D05120A—Silicon Carbide Schottky Diode

## Z-REC™ RECTIFIER

$V_{RRM} = 1200\text{ V}$   
 $I_F = 5\text{ A}$   
 $Q_c = 34.5\text{ nC}$

### Features

- 1.2kV Schottky Rectifier
- Zero Reverse Recovery Current
- High-Frequency Operation
- Temperature-Independent Switching
- Extremely Fast Switching

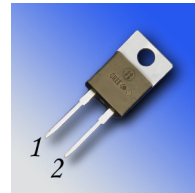
### Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

### Applications

- Switch Mode Power Supplies
- Power Factor Correction
- Motor Drives

### Package



TO-220-2



Part Number	Package	Marking
C4D05120A	TO-220-2	C4D05120

### Maximum Ratings ( $T_c=25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions	Note
$V_{RRM}$	Repetitive Peak Reverse Voltage	1200	V		
$V_{RSM}$	Surge Peak Reverse Voltage	1300	V		
$V_R$	DC Peak Reverse Voltage	1200	V		
$I_{F(AVG)}$	Maximum DC Current	8.2	A	$T_c=135^\circ\text{C}$ , no AC component	
$I_{FRM}$	Repetitive Peak Forward Surge Current	26 18	A	$T_c=25^\circ\text{C}$ , $t_p=10\text{ ms}$ , Half Sine Pulse $T_c=110^\circ\text{C}$ , $t_p=10\text{ ms}$ , Half Sine Pulse	
$I_{FSM}$	Non-Repetitive Forward Surge Current	46 36	A	$T_c=25^\circ\text{C}$ , $t_p=10\text{ ms}$ , Half Sine Pulse $T_c=110^\circ\text{C}$ , $t_p=10\text{ ms}$ , Half Sine Pulse	
$P_{tot}$	Power Dissipation	81 35	W	$T_c=25^\circ\text{C}$ $T_c=110^\circ\text{C}$	
$T_c$	Maximum Case Temperature	135	$^\circ\text{C}$		
$T_j$	Operating Junction Range	-55 to +175	$^\circ\text{C}$		
$T_{stg}$	Storage Temperature Range	-55 to +135	$^\circ\text{C}$		
	TO-220 Mounting Torque	1 8.8	Nm lbf-in	M3 Screw 6-32 Screw	

### Electrical Characteristics

Symbol	Parameter	Typ.	Max.	Unit	Test Conditions	Note
$V_F$	Forward Voltage	1.4 1.9	1.8 3	V	$I_F = 5\text{ A}$ $T_J = 25^\circ\text{C}$ $I_F = 5\text{ A}$ $T_J = 175^\circ\text{C}$	
$I_R$	Reverse Current	20 40	150 300	$\mu\text{A}$	$V_R = 1200\text{ V}$ $T_J = 25^\circ\text{C}$ $V_R = 1200\text{ V}$ $T_J = 175^\circ\text{C}$	
$Q_C$	Total Capacitive Charge	34.5		nC	$V_R = 1200\text{ V}$ , $I_F = 5\text{ A}$ $di/dt = 200\text{ A}/\mu\text{s}$ $T_J = 25^\circ\text{C}$	
C	Total Capacitance	390 27 20		pF	$V_R = 0\text{ V}$ , $T_J = 25^\circ\text{C}$ , $f = 1\text{ MHz}$ $V_R = 400\text{ V}$ , $T_J = 25^\circ\text{C}$ , $f = 1\text{ MHz}$ $V_R = 800\text{ V}$ , $T_J = 25^\circ\text{C}$ , $f = 1\text{ MHz}$	

Note:

1. This is a majority carrier diode, so there is no reverse recovery charge.

### Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Unit	Test Conditions	Note
$R_{\theta JC}$	Thermal Resistance from Junction to Case	1.85		$^\circ\text{C}/\text{W}$		

### Typical Performance

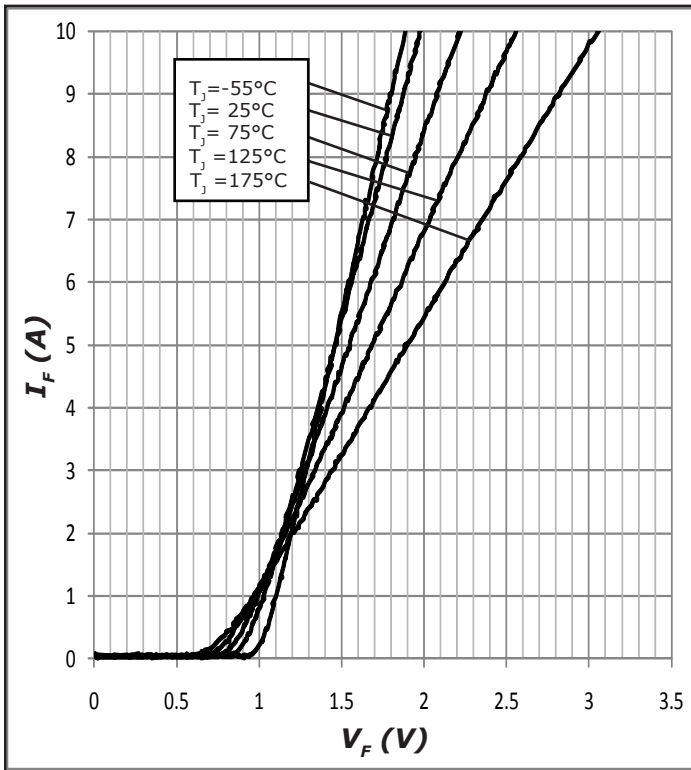


Figure 1. Forward Characteristics

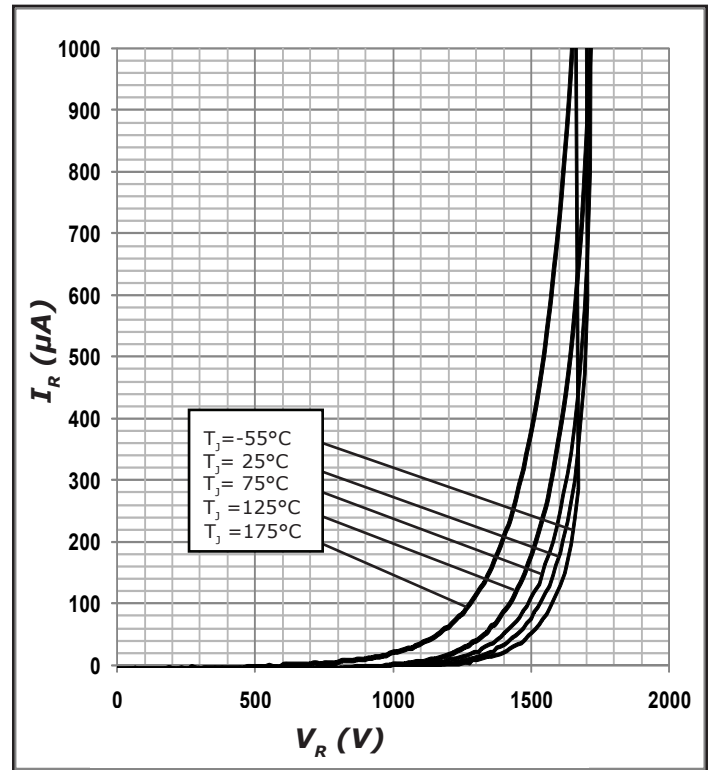


Figure 2. Reverse Characteristics

# Typical Performance

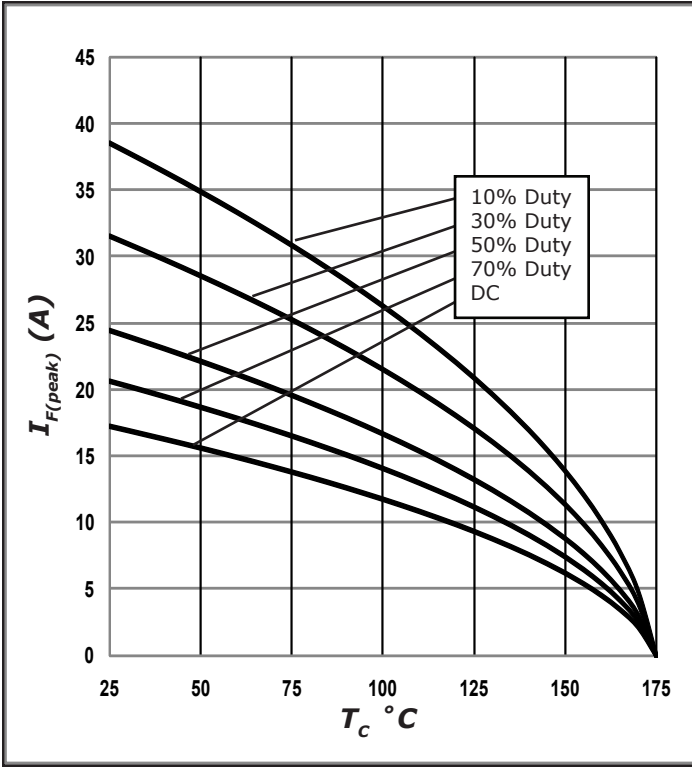


Figure 3. Current Derating

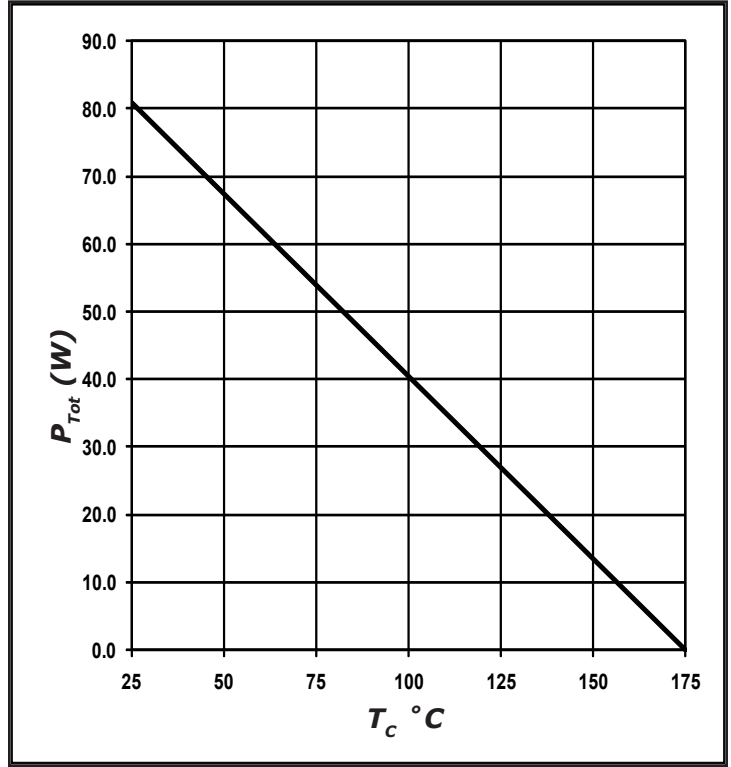


Figure 4. Power Derating

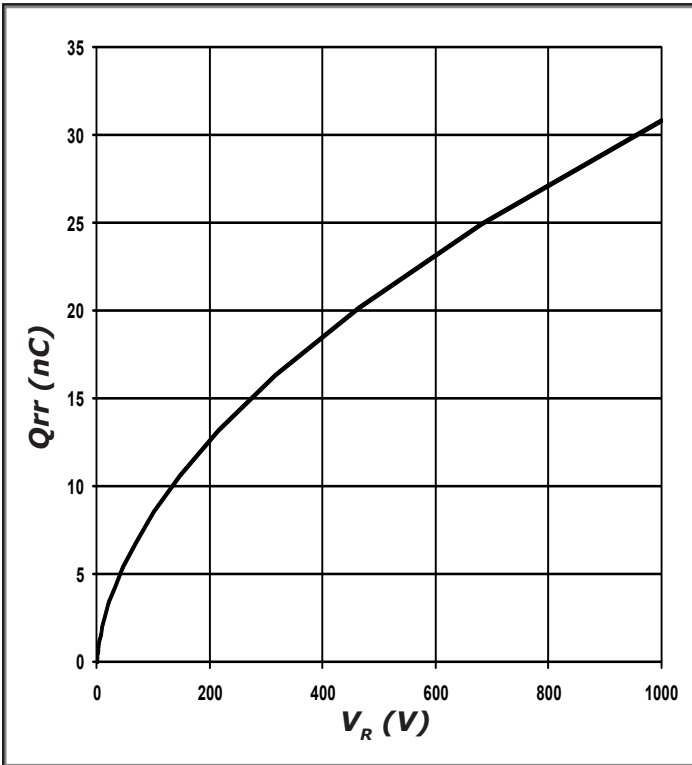


Figure 5. Recovery Charge vs. Reverse Voltage

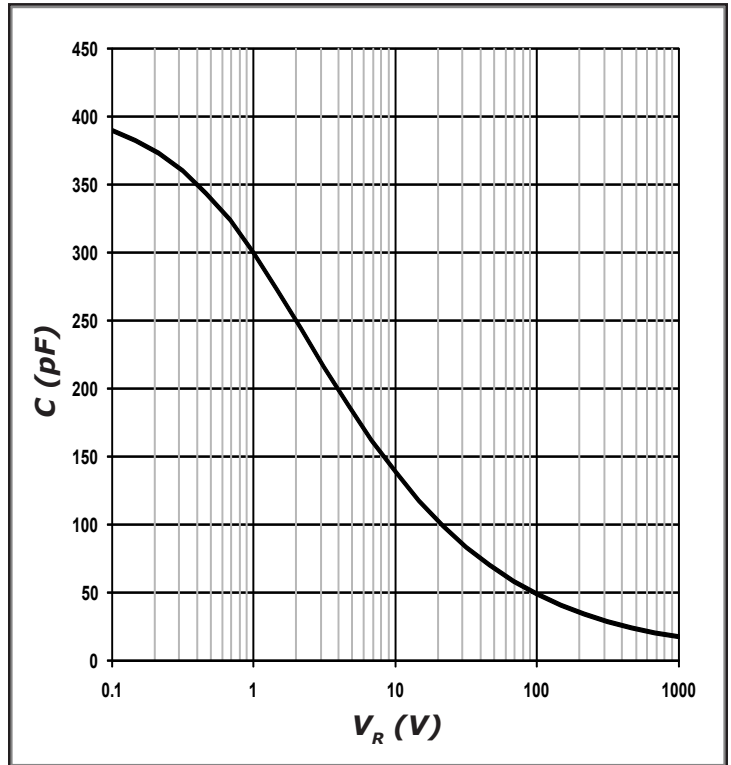


Figure 6. Capacitance vs. Reverse Voltage

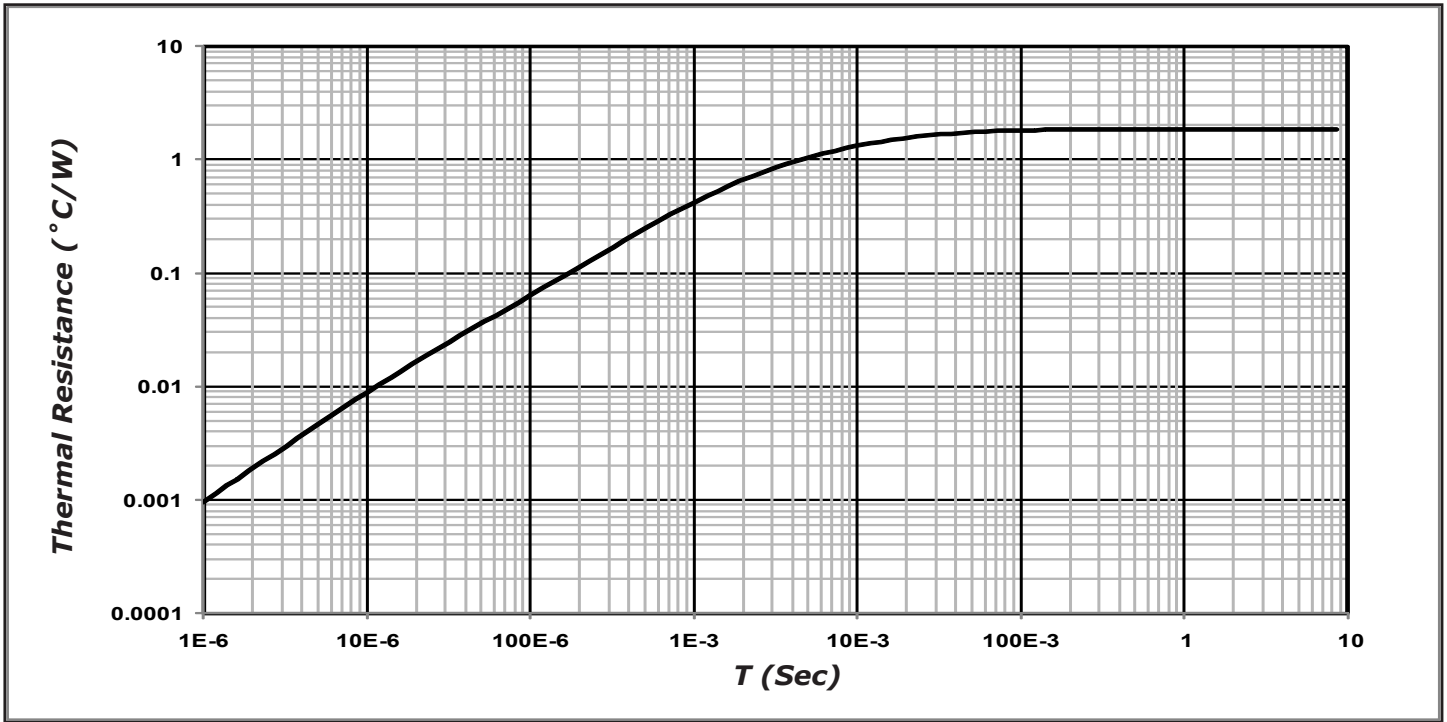
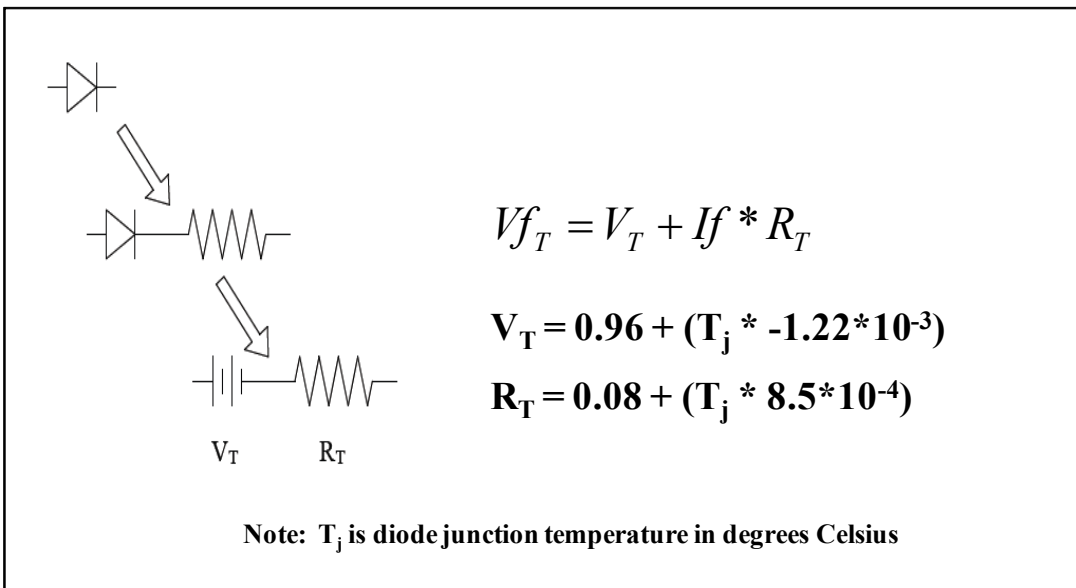


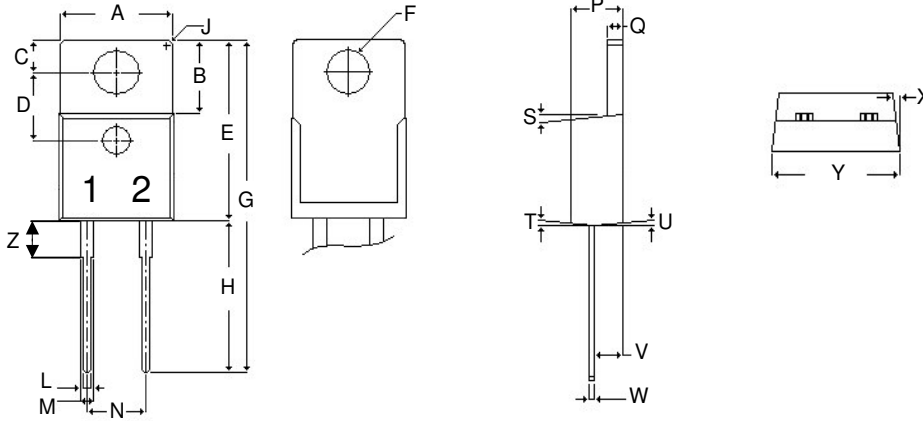
Figure 7. Transient Thermal Impedance

## Diode Model



## Package Dimensions

Package TO-220-2

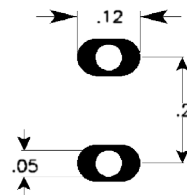


POS	Inches		Millimeters	
	Min	Max	Min	Max
A	.381	.410	9.677	10.414
B	.235	.255	5.969	6.477
C	.100	.120	2.540	3.048
D	.223	.337	5.664	8.560
E	.590	.615	14.986	15.621
F	.143	.153	3.632	3.886
G	1.105	1.147	28.067	29.134
H	.500	.550	12.700	13.970
J	R 0.197		R 0.197	
L	.025	.036	.635	.914
M	.045	.055	1.143	1.397
N	.195	.205	4.953	5.207
P	.165	.185	4.191	4.699
Q	.048	.054	1.219	1.372
S	3°	6°	3°	6°
T	3°	6°	3°	6°
U	3°	6°	3°	6°
V	.094	.110	2.388	2.794
W	.014	.025	.356	.635
X	3°	5.5°	3°	5.5°
Y	.385	.410	9.779	10.414
Z	.130	.150	3.302	3.810

NOTE:

1. Dimension L, M, W apply for Solder Dip Finish

## Recommended Solder Pad Layout



TO-220-2

Part Number	Package	Marking
C4D05120A	TO-220-2	C4D05120

"The levels of environmentally sensitive, persistent biologically toxic (PBT), persistent organic pollutants (POP), or otherwise restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2002/95/EC on the restriction of the use of certain hazardous substances in electrical and electronic equipment (RoHS), as amended through April 21, 2006."

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